

# 1.5MHz, 1.2A Synchronous Step-Down Converter

# with Force PWM Mode

### **FEATURES**

- High Efficiency: Up to 96%(@3.3V)
- 1.5MHz Constant Frequency Operation
- Force PWM Operation
- 1.2A Output Current
- No Schottky Diode Required
- 2.5V to 5.5V Input Voltage Range
- Output Voltage as Low as 0.6V
- 100% Duty Cycle in Dropout
- Slope Compensated Current Mode Control for Excellent Line and Load Transient Response
- Short Circuit Protection
- Thermal Fault Protection
- Inrush Current Limit and Soft Start
- Input over voltage protection (OVP)
- <1µA Shutdown Current</li>
- SOT23-5 Package

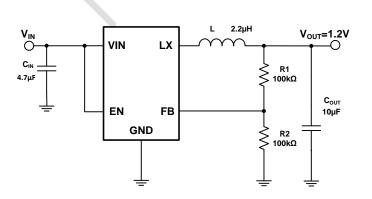
#### **GENERAL DESCRIPTION**

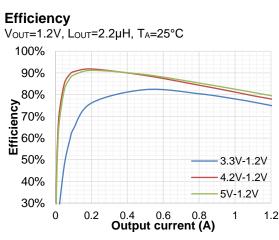
The TMI3408F is a constant frequency 1.5MHz, peak current mode step-down converter with force PWM operation mode. The device integrates a main switch and a synchronous rectifier for high efficiency without an external Schottky diode. The output voltage can be regulated as low as 0.6V. The TMI3408F can also run at 100% duty cycle for low dropout operation, extending battery life in portable system. This device adopts peak current mode control and force PWM mode and has fast load transient response.

### APPLICATIONS

- Cellular and Smart Phones
- Wireless and DSL Modems
- PDA/MID/PAD
- Digital Still and Video Cameras

### **TYPICAL APPILCATION**





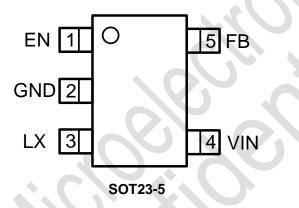
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# ABSOLUTE MAXIMUM RATINGS (Note 1)

Parameter	Value	Unit
Input Supply Voltages	-0.3~6.5	V
LX Voltages	-0.3~6.5	V
EN, FB Voltage	-0.3~6.5	V
Storage Temperature Range	-65~150	°C
Junction Temperature (Note 2)	-40~150	°C
Power Dissipation	600	mW
Lead Temperature Soldering,10Sec	260	٥°C

### **PIN CONFIGURATION**



#### Top Mark: T5FXXX (T5F: Device Code, XXX: Inside Code)

Part Number	Package	Top mark	Quantity/ Reel
TMI3408F	SOT23-5	T5FXXX	3000

TMI3408F devices are Pb-free and RoHS compliant.



### **PIN FUNCTIONS**

Pin	Name	Function			
		Chip Enable Pin. Drive EN above 1.5V to turn on the part. Drive EN below 0.3V			
1	EN	to turn it off. Do not leave EN floating.			
2	GND	Ground Pin			
3	LX	Power Switch Output. It is the switch node connection to Inductor.			
4	VIN	Power Supply Input. Must be closely decoupled to GND with a $4.7\mu$ F or greater ceramic capacitor.			
5	FB	Output Voltage Feedback Pin.			

#### **ESD RATING**

Items Description		Value	Unit
Vesd_hbm	Human Body Model for all pins	±2000	V
Vesd_cdm	Charge Device Model for all pins	±1000	V

**JEDEC specification JS-001** 

### **RECOMMENDED OPERATING CONDITIONS**

Items	Description	Min	Max	Unit
Voltage Range	IN	2.5	5.5	V
TJ	Operating Junction Temperature Range	-40	125	°C

# THERMAL RESISITANCE (Note 3)

Items	Description	Value	Unit
θ <sub>JA</sub>	Junction-to-ambient thermal resistance	200	°C/W
θ」	Junction-to-case thermal resistance	65	°C/W



## **ELECTRICAL CHARACTERISTICS**

#### (VIN=3.7V, VOUT=1.2V, TA = 25°C, unless otherwise noted.)

Parameter	Test Conditions	Min	Тур	Max	Unit
Input Voltage Range		2.5		5.5	V
OVP Threshold		5.8	6.0	6.2	V
UVLO Threshold			2.4	2.5	V
Quiescent Current	V <sub>EN</sub> =2.0V, V <sub>FB</sub> =V <sub>REF</sub> x105%		180	300	μA
Standby Current	V <sub>EN</sub> =2.0V, I <sub>OUT</sub> =0A		2	6	mA
Shutdown Current	V <sub>EN</sub> =0V		0.1	5	μA
Regulated Feedback Voltage	$T_A = 25^{\circ}C$	0.588	0.600	0.612	V
	V <sub>OUT</sub> =100%		1.5		MHz
Oscillation Frequency	V <sub>OUT</sub> =0V		400		kHz
On Resistance of PMOS	I <sub>LX</sub> =100mA		0.29		Ω
On Resistance of NMOS	I <sub>LX</sub> =-100mA		0.18		Ω
Minimum On Time	$\mathbf{C}$		90		ns
Peak Current Limit	V <sub>IN</sub> =5V, V <sub>OUT</sub> =1.2V, L=4.7µH/2A	1.5			А
Negative Current Limit of LS_MOSFET			-0.4		А
EN Input Low Level	11 YN		2	0.3	V
EN Input High Level		1.5			V
EN Leakage Current			±0.01	±1.0	μA
LX Leakage Current	$V_{EN}=0V, V_{IN}=V_{LX}=5V$		±0.01	±1.0	μA
Thermal Shutdown Threshold (Note 4)			150		°C
Thermal Shutdown Hysteresis (Note 4)			25		°C

**Note 1**: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2**:  $T_J$  is calculated from the ambient temperature  $T_A$  and power dissipation  $P_D$  according to the following formula:  $T_J = T_A + (P_D) \times \theta_{JA}$ .

Note 3: Measured on JESD51-7, 4-layer PCB.

Note 4: Guaranteed by design.

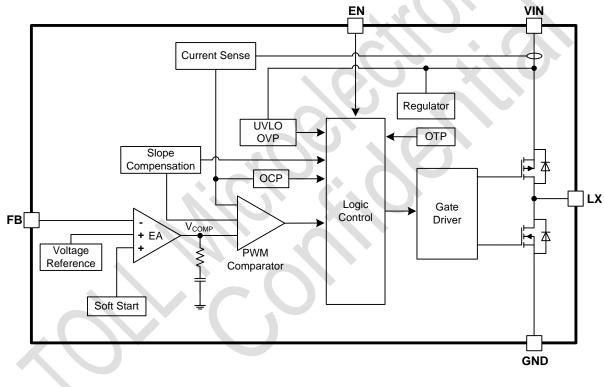


### **FUNCTION DESCRIPTION**

The TMI3408F is a high performance 1.2A, 1.5MHz monolithic step-down converter with force PWM operation mode. The TMI3408F requires few external power components (C<sub>in</sub>, C<sub>out</sub> and L). The output voltage can be programmed with external feedback to any voltage, ranging from 0.6V to the input voltage.

At dropout, the converter duty cycle increases to 100% and the output voltage tracks the input voltage minus the  $R_{DS(ON)}$  drop of the high-side MOSFET.

The internal error amplifier and compensation provides excellent transient response, load, and line regulation. Soft start function prevents input inrush current and output overshoot during start up.



## FUNCTIONAL BLOCK DIAGRAM

Figure 2. TMI3408F Block Diagram



### **APPLICATION INFORMATION**

#### Setting the Output Voltage

Figure 1 shows the basic application circuit for the TMI3408F. The TMI3408F can be externally programmed. Resistors R1 and R2 in Figure 1 program the output to regulate at a voltage higher than 0.6V. The external resistor sets the output voltage according to the following equation:

$$V_{OUT} = 0.6 \times (1 + \frac{R_1}{R_2})$$
$$R_1 = (V_{OUT} / 0.6 - 1) \times R_2$$

#### **Inductor Selection**

For most designs, 2.2µH inductance can satisfy most application conditions. Inductance value is related to inductor ripple current value, input voltage, output voltage setting and switching frequency. The inductor value can be derived from the following equation:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times f_{OSC}}$$

Where  $\Delta I_L$  is inductor ripple current. Large value inductors result in lower ripple current and small value inductors result in high ripple current, so inductor value has effect on output voltage ripple value. TMI3408F is force PWM operation mode. In dull load condition, the average inductor current is zero and valley inductor current is  $-\Delta I_L/2$ . The larger inductance value, the more negative valley inductor current. Because of the negative valley inductor current limitation, the recommended smallest inductance value for TMI3408F application is 2.2µH or larger inductance.

#### **Input Capacitor Selection**

The input capacitor reduces the surge current drawn from the input and switching noise from the device.

The input capacitor impedance at the switching frequency should be less than input source impedance to prevent high frequency switching current passing to the input.

A low ESR input capacitor sized for maximum RMS current must be used. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR and small temperature coefficients.

A 4.7µF ceramic capacitor for most applications is sufficient. A large value may be used for improved input voltage filtering.

#### **Output Capacitor Selection**

The output capacitor is required to keep the output voltage ripple small and to ensure regulation loop stability. The output capacitor must have low impedance at the switching frequency. Ceramic capacitors with X5R or X7R dielectrics are recommended due to their low ESR and high ripple current ratings. The output ripple  $V_{OUT}$  is determined by:

$$\Delta V_{OUT} \leq \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{OSC} \times L} \times \left( ESR + \frac{1}{8 \times f_{osc} \times C3} \right)$$



An effective 10µF or larger value ceramic capacitor can satisfy most applications.

#### Layout Consideration

When laying out the printed circuit board, the Following checking should be used to ensure proper operation of the TMI3408F. Check the following in your layout:

1. The power traces, consisting of the GND trace, the LX trace and the IN trace should be kept short, direct and wide.

2. Does the (+) plates of  $C_{in}$  connect to IN as closely as possible. This capacitor provides the AC current to the internal power MOSFETs.

3. Keep the switching node, LX, away from the sensitive VOUT node.

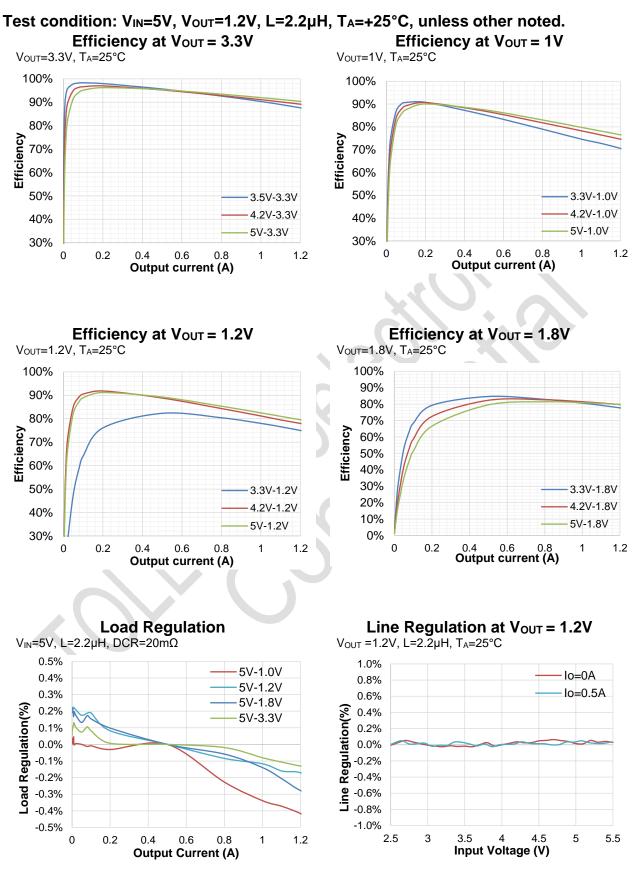
4. Keep the (-) plates of  $C_{in}$  and  $C_{out}$  as close as possible

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### **TYPICAL PERFORMANCE CHARACTERISTICS**



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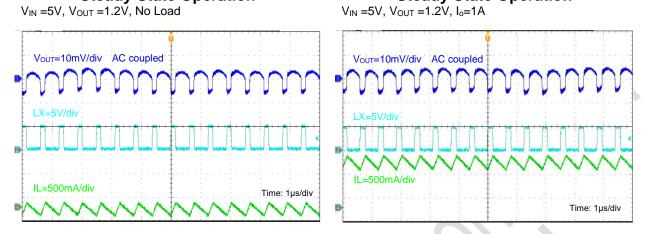
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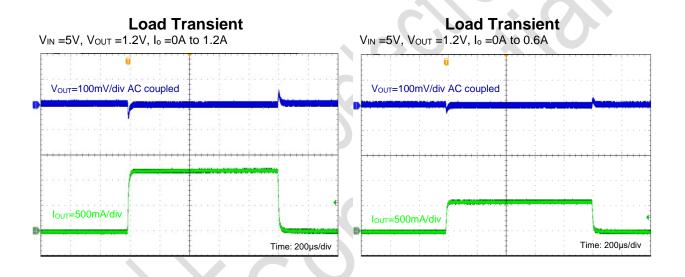


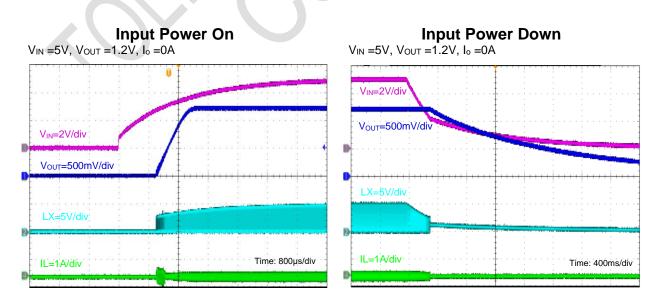
# TYPICAL PERFORMANCE CHARACTERISTICS (continued)

**Steady State Operation** 

**Steady State Operation** V<sub>IN</sub> =5V, V<sub>OUT</sub> =1.2V, I<sub>o</sub>=1A







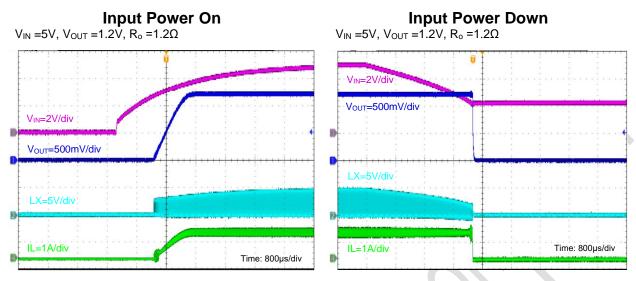
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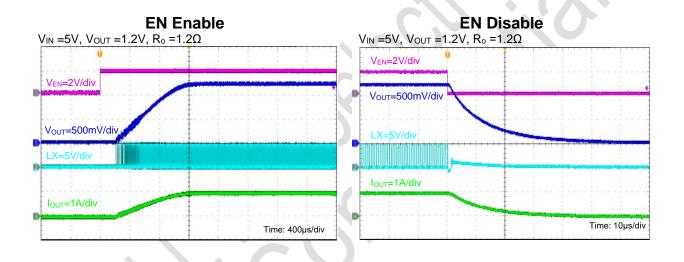
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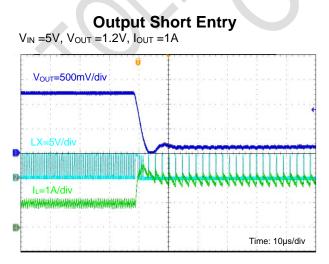


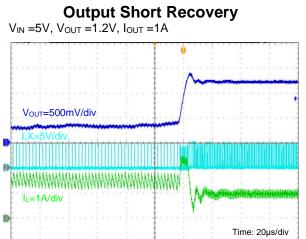
# TYPICAL PERFORMANCE CHARACTERISTICS (continued)





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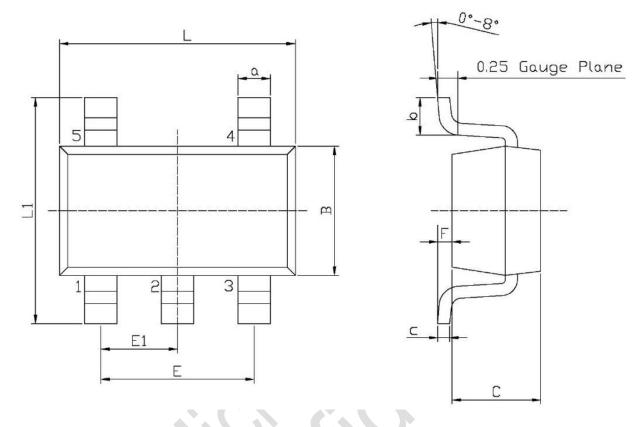






### PACKAGE INFORMATION

SOT23-5



Unit: mm

<b>C</b> 1	Sumbol	Dimensions In Millimeters		Cumbal	Dimensions In Millimeters		
	Symbol	Min	Max	Symbol	Min	Max	
	L	2.82	3.02	E1	0.85	1.05	
	В	1.50	1.70	а	0.35	0.50	
	С	0.90	1.30	С	0.10	0.20	
	L1	2.60	3.00	b	0.35	0.55	
	E	1.80	2.00	F	0	0.15	

#### Note:

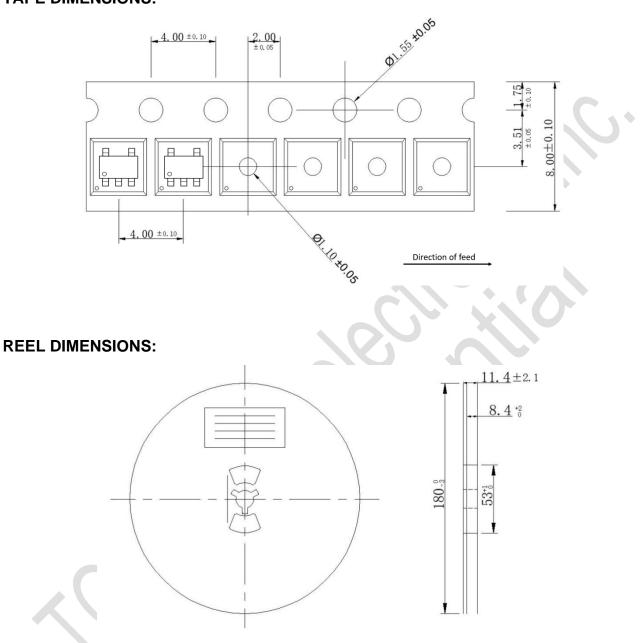
- 1) All dimensions are in millimeters.
- 2) Package length does not include mold flash, protrusion or gate burr.
- 3) Package width does not include inter lead flash or protrusion.
- 4) Lead popularity (bottom of leads after forming) shall be 0.10 millimeters max.
- 5) Pin 1 is lower left pin when reading top mark from left to right.





# TAPE AND REEL INFORMATION

#### TAPE DIMENSIONS:



#### Note:

- 1) All Dimensions are in Millimeter
- 2) Quantity of Units per Reel is 3000
- 3) MSL level is level 3.